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CD4099BC 8-Bit Addressable Latch

General Description

The CD4099BC is an 8-bit addressable latch with three address inputs (A0–A2), an active low enable input (\overline{E}) , active high clear input (CL), a data input (D), and eight outputs (Q0–Q7).

Data is entered into a particular bit in the latch when that bit is addressed by the address inputs and the enable (\overline{E}) is LOW. Data entry is inhibited when enable (\overline{E}) is HIGH.

When clear (CL) and enable (\overline{E}) are HIGH, all outputs are LOW. When clear (CL) is HIGH and enable (\overline{E}) is LOW, the channel demultiplexing occurs. The bit that is addressed has an active output which follows the data input while all unaddressed bits are held LOW. When operating in the addressable latch mode $(\overline{E}=CL=LOW)$, changing more than one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode $(\overline{E}=HIGH,\,CL=LOW)$.

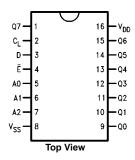
Features

- Wide supply voltage range: 3.0V to 15V
- High noise immunity: 0.45 V_{DD} (typ.)
- Low power TTL: fan out of 2 driving 74L compatibility: or 1 driving 74LS
- Serial to parallel capability
- Storage register capability
- Random (addressable) data entry
- Active high demultiplexing capability
- Common active high clear

Ordering Code:

Order Number	Package Number	Package Description				
CD4099BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				

Connection Diagram



Truth Table

Mode Selection								
E	CL	Addressed	Unaddressed	Mode				
		Latch	Latch Latch					
L	L	Follows Data	Holds Previous Data	Addressable Latch				
Н	L	Holds Previous Data	Holds Previous Data	Memory				
L	Н	Follows Data	Reset to "0"	Demultiplexer				
Н	Н	Reset to "0"	Reset to "0"	Clear				

Absolute Maximum Ratings(Note 1)

(Note 2)

DC Supply Voltage (V_{DD}) $-0.5 \text{ to } +18 \text{ V}_{DC}$ Input Voltage (V_{IN}) $-0.5 \text{ to } V_{DD} +0.5 \text{ V}_{DC}$

Storage Temperature

Range (T_S) -65° C to $+150^{\circ}$ C

Power Dissipation (P_D)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3.0 to 15 V_{DC} Input Voltage (V_{IN}) 0 to V_{DD} V_{DC} Operating Temperature Range (T_A) -55°C to +125°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	–55°C		+25°C			+125°C		Units
Cyllibol		Conditions	Min	Max	Min	Тур	Max	Min	Max	Ointo
I _{DD}	Quiescent Device	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		5.0		0.02	5.0		150	
	Current	$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		10		0.02	10		300	μΑ
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		20		0.02	20		600	
V _{OL}	LOW Level	$ I_O \le 1\mu A$								
	Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		V _{DD} = 15V		0.05		0	0.05		0.05	
V _{OH}	HIGH Level	I _O ≤ 1 μA								
	Output Voltage	$V_{DD} = 5V$	4.95		4.95	5		4.95		
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		V _{DD} = 15V	14.95		14.95	15		14.95		
V _{IL}	LOW Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$		1.5		2.25	1.5		1.5	
	Input Voltage	$V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$		3.0		4.5	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$		4.0		6.75	4.0		4.0	
V _{IH}	HIGH Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	3.5		3.5	2.75		3.5		
	Input Voltage	$V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$	7.0		7.0	5.5		7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$	11.0		11.0	8.25		11.0		
l _{OL}	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4		
I _{OH}	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		-0.51	-0.88		-0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4		
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10 ⁻⁵	-0.1		-1.0	μА
		$V_{DD} = 15V, \ V_{IN} = 15V$		0.1		10 ⁻⁵	0.1		1.0	μА

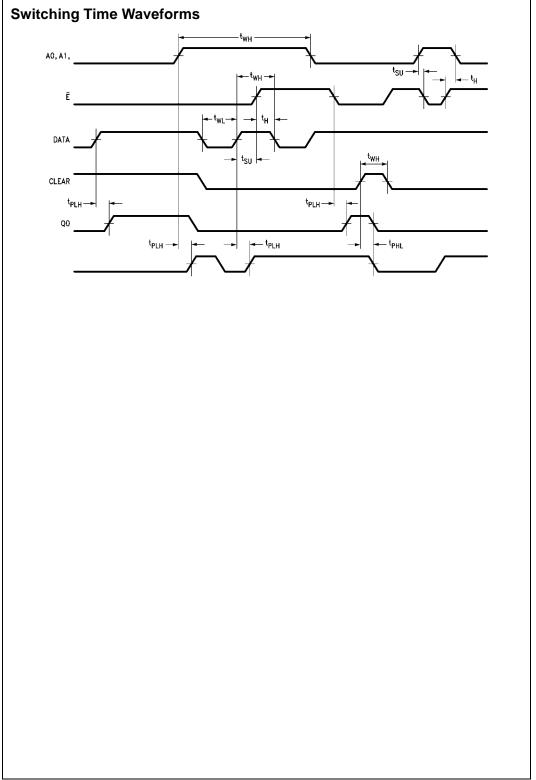
Note 3: I_{OH} and I_{OL} are tested one output at a time.

$\begin{tabular}{ll} AC Electrical Characteristics & (Note 4) \\ T_A = 25^{\circ}C, \ C_L = 50 \ pF, \ R_L = 200k, \ Input \ t_r = t_f = 20 \ ns, \ unless \ otherwise \ noted \end{tabular}$

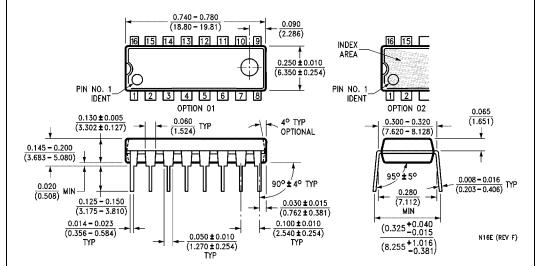
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHL} , t _{PLH}	Propagation Delay	$V_{DD} = 5V$		200	400	
	Data to Output	V _{DD} = 10V		75	150	ns
		V _{DD} = 15V		50	100	
t _{PLH} , t _{PHL}	Propagation Delay	$V_{DD} = 5V$		200	400	
	Enable to Output	V _{DD} = 10V		80	160	ns
		V _{DD} = 15V		60	120	
t _{PHL}	Propagation Delay	$V_{DD} = 5V$		175	350	
	Clear to Output	V _{DD} = 10V		80	160	ns
		V _{DD} = 15V		65	130	
t _{TLH} , t _{THL}	Propagation Delay	$V_{DD} = 5V$		225	450	
	Address to Output	V _{DD} = 10V		100	200	ns
		V _{DD} = 15V		75	150	
t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$		100	200	
	(Any Output)	V _{DD} = 10V		50	100	ns
		V _{DD} = 15V		40	80	
T _{WH} , T _{WL}	Minimum Data	$V_{DD} = 5V$		100	200	
	Pulse Width	V _{DD} = 10V		50	100	ns
		V _{DD} = 15V		40	80	
t _{WH} , t _{WL}	Minimum Address	V _{DD} = 5V		200	400	
	Pulse Width	V _{DD} = 10V		100	200	ns
		V _{DD} = 15V		65	125	
t _{WH}	Minimum Clear	$V_{DD} = 5V$		75	150	
	Pulse Width	V _{DD} = 10V		40	75	ns
		V _{DD} = 15V		25	50	
t _{SU}	Minimum Set-Up Time	$V_{DD} = 5V$		40	80	
	Data to E	V _{DD} = 10V		20	40	ns
		V _{DD} = 15V		15	30	
t _H	Minimum Hold Time	$V_{DD} = 5V$		60	120	
	Data to E	V _{DD} = 10V		30	60	ns
		V _{DD} = 15V		25	50	
t _{SU}	Minimum Set-Up Time	$V_{DD} = 5V$		-15	50	
	Address to E	V _{DD} = 10V		0	30	ns
		V _{DD} = 15V		0	20	
t _H	Minimum Hold Time	V _{DD} = 5V		-50	15	
	Address to E	V _{DD} = 10V		-20	10	ns
		V _{DD} = 15V		-15	5	
C _{PD}	Power Dissipation Capacitance	Per Package (Note 5)		100		pF
C _{IN}	Input Capacitance	Any Input	-	5.0	7.5	pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

Note 5: Dynamic power dissipation (P_D) is given by: $P_D = (C_{PD} + C_L) \ V_{CC}^2 f + P_Q$; where $C_L = load$ capacitance; f = f frequency of operation; for further details, see application note AN-90, "54C/74C Family Characteristics".



Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

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